LITE-ON SEMICONDUCTOR

GBU1004 thru GBU1010

GLASS PASSIVATED BRIDGE RECTIFIERS

REVERSE VOLTAGE – 400 to 1000 Volts
FORWARD CURRENT – 10 Amperes

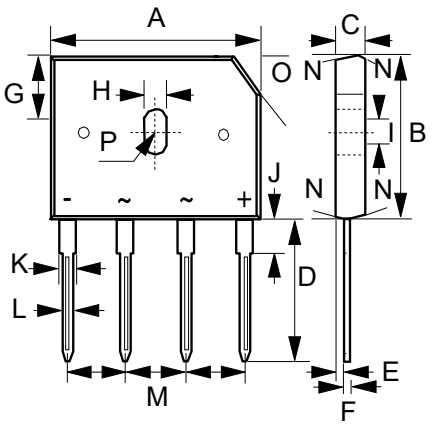
FEATURES

- Rating to 1000V PRV.
- Ideal for printed circuit board
- Reliable low cost construction utilizing molded plastic technique.
- UL recognition file # E95060

MECHANICAL DATA

- Case: GBU
- Case Material: Plastic material, UL flammability classification 94V-0
- Polarity Indicator: Symbol molded on body
- Weight: 3.72 grams (Approximate)

GBU



GBU		
DIM	MIN	MAX
A	21.80	22.30
B	18.30	18.80
C	3.30	3.56
D	17.50	18.00
E	0.76	1.00
F	0.46	0.56
G	7.40	7.90
H	3.50	4.10
I	1.65	2.16
J	2.25	2.75
K	1.95	2.35
L	1.02	1.27
M	4.83	5.33
N	7.0° TYPICAL	
O	(3.2) x 45°	
P	1.90 PADIUS	
All dimension in millimeter		

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

ABSOLUTE RATINGS

PARAMETER	SYMBOL	GBU1004	GBU1006	GBU1008	GBU1010	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	400	600	800	1000	V
Maximum DC blocking voltage	V_{DC}	400	600	800	1000	V
Average rectified output current per device with heatsink (Note 2) without heatsink @ T_C=100°C	$I_{(AV)}$	10 3.2				A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load @ T_A=25°C @ T_A=125°C	I_{FSM}	240 220				A
Peak forward surge current 1ms single half sine-wave superimposed on rated load @ T_A=25°C @ T_A=125°C	I_{FSM}	480 440				A
I^2t rating for fusing (t = 8.3 ms) @ T_A=25°C	I^2t	239				A^2S
Mounting Torque (recommended torque: 0.5 N.m)	TOR	0.8				N.m
Operating and storage temperature range	T_J , T_{STG}	-55 to +150				°C

STATIC ELECTRICAL CHARACTERISTICS

PARAMETER	TEST CONDITION		SYMBOL	MAX	UNIT
Forward voltage	I_F = 5.0A	T_J = 25°C	V_F	1.0	V
	I_F = 10A	T_J = 25°C		1.2	
Leakage current	V_R at rated	T_J = 25°C T_J = 125°C	I_R	5 500	uA
Typical junction capacitance (Note 1)			C_J	60	pF

THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	TYP.	UNIT
Typical thermal resistance	$RthJ_C$ (Note 2) $RthJ_C$ (without heatsink) $RthJ_A$ (without heatsink)	2.0 5.6 22	°C/W

REV.10, Mar-2019, KBDJ04

Note :

(1) Measured at 1.0MHz and applied reverse voltage of 4.0V DC

(2) Thermal resistance junction to case and ambient in accordance with JESD-51. Device mounted on 150mm * 150mm * 1.6mm Cu plate heatsink.

RATING AND CHARACTERISTIC CURVES
GBU1004 thru GBU1010

LITEON

FIG.1- FORWARD CURRENT DERATING CURVE

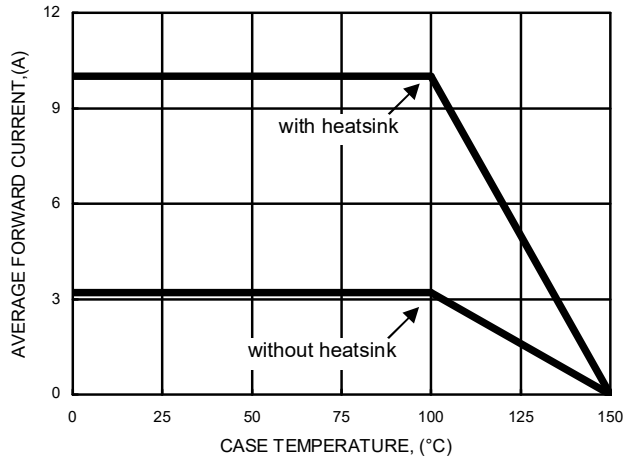


FIG.2- MAXIMUM NON-REPETITIVE SURGE CURRENT

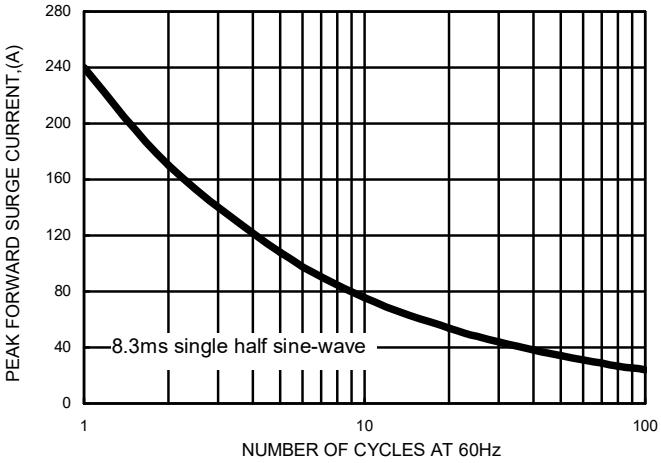


FIG.3- TYPICAL FORWORD CHARACTERISTICS

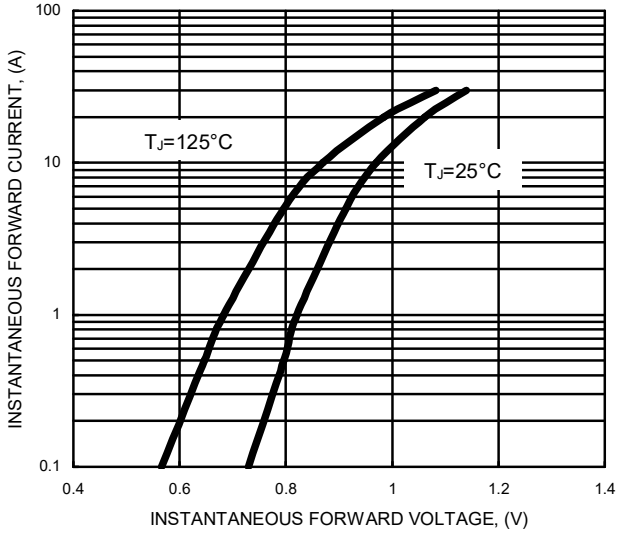


FIG.4- TYPICAL JUNCTION CAPACITANCE

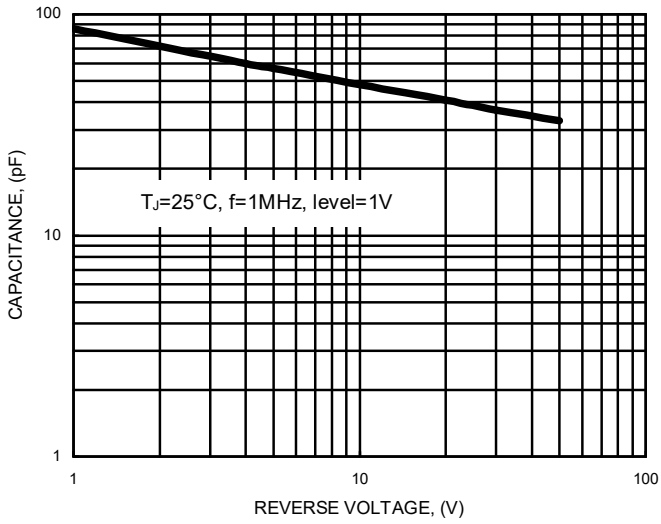


FIG.5- TYPICAL REVERSE CHARACTERISTICS

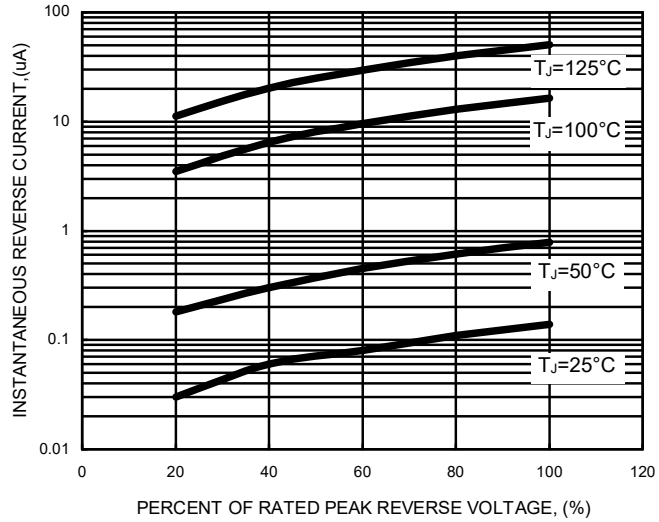
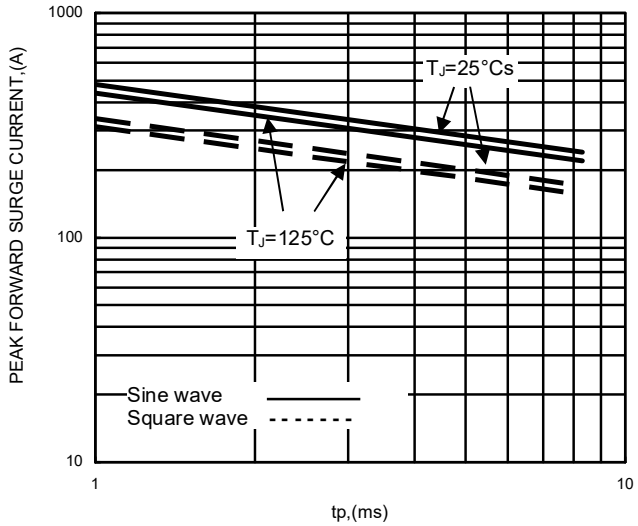


FIG.6- NON-REPETITIVE SURGE CURRENT



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